Ammonia Gas Sensing Performance of Polyaniline-SnO₂

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Abstract- Nanocomposite samples of polyaniline-SrO₂ were prepared by loading pure polyaniline (PANI) by post-transition metal oxide (SnO₂) as an additive. Nanocomposites of PANI-SnO₂ were prepared with three different molar concentrations of SnO₂ using in situ oxidative polymerization of aniline in presence of SnO₂. UV-Visible spectroscopy of prepared samples of PANI-SnO2 revealed emraldine salt phase of polyaniline. XRD patterns reflect the nano crystallite size of PANI-SnO₂ composite. Transmission electron microscopic study confirms the nano-sized of prepared composite samples. Scanning Electron Microscopy of nanocomposite showed change in surface morphology with the variation in concentration of SnO₂. PANI-SnO₂ (0.25 M) nanocomposite exhibit a response to CO2 at quit higher temperature. The effects of surface microstructure with variation in SnO₂ concentrations and surface activation with CuO on the sensor response, selectivity, recovery and long term durability of the sensor in the presence of NH3 and other gases were studied and discussed. SnO₂ loaded PANI is outstanding in promoting the NH₃ gas sensing performance of the material. CuO as an activator in PANI-SnO₂ enhances ammonia sensing performance of the prepared sensor samples at room temperature.

Keywords— Polyaniline, SnO₂, Nanocomposite, Ammonia gas Sensor, Room temperature.

I. INTRODUCTION

In everyday life, gas sensors have a broad range of increasing applications regarding environmental monitoring and protection, clinical and health care, food processing, industrial development, etc. Semiconducting metal oxides have been studied extensively for sensing different gases. In particular SnO₂ [1], ZnO [2-7], Ferrites [8], LaAlO₃ [9], Cu₂S [10], etc. are studied extensively. However, there are some significant disadvantages of metal oxide gas sensors such as high operating temperature, lack of selectivity and sensitivity at ambient temperature, instability over long period, etc. Recent developments in the field of conducting polymer promise future progress in certain areas of modern technology such as microelectronics, sensors, biosensors or chemical and biochemical engineering [11-13]. Gas sensors are important for monitoring environmental quality and safety. Hazardous gases, like liquefied petroleum gas (LPG), have been widely used for several industrial and domestic applications. The development of gas sensors is imperative due to the concern of safety requirements, particularly for detection of LPG. Gas sensing devices based on inorganic materials, generally have low selectivity to specific target gases and operating temperature [14-16] thus suffering with high power consumption, reduced sensor life, limited portability, etc. In order to overcome these problems recently, conducting polymers found suitable as a gas sensor. Recent studies showed that, conducting polymers are sensitive to wide range of gases and vapors [17-18, 22-26].

However, the problems with the conducting polymers are their low processability, their mechanical strength [19-21], poor chemical stability, etc. Out of various conducting polymers, Polyaniline (PANI) is most studied for its various applications. Gas sensors based on PANI show major disadvantage of poor selectivity for particular gas against other gases. Because conducting PANI can be doped and undoped by redox reactions and their doping level get altered by transferring electrons from the gases or to the gases. Electron acceptor (oxidizing) gases such as NO2, Cl2 etc. remove electrons from the aromatic ring of PANI which shows enhanced doping level and electrical conductivity of PANI. An opposite process takes place when electron donating (reducing) gases such as NH₃, H₂S, C₂H₅OH, etc. react with active layer of PANI. It is a major challenge to improve selectivity and stability in case of gas sensors based on PANI. As an option, composition of organic and inorganic materials, PANI and metal particles, provides enhancement of sensor characteristics such as selectivity, sensitivity, etc. and mechanical strength. Recently researchers are working with many of such composition like PANI-SnO2 as ammonia sensor [22] PANI-ZnO [23] and PANI- CdS thin films as LPG sensor [24]. PANI-WO₃ thick films showed remarkable response to LPG [25]. PANI-Cu pellets were fabricated for chloroform vapor sensing [26].

In the present work, efforts are taken to develop the ammonia sensor by modifying PANI and its compositions with SnO₂, which could be able to detect various gases at trace level (ppm, ppb or even sub-ppb level).

II. EXPERIMENTAL DETAILS

All reagents Sncl₂, ethanol, liquid ammonia, Nitric acid, Aniline, Ammonium per sulphate were purchased from sigma. All chemicals were of analytical grade and used as received.

II. (A) SYNTHESIS OF MATERIALS

Nanostructured SnO₂ is synthesized by disc type Ultra sonicated microwave assisted centrifuge technique. Initially, 1M solution of SnCl₂ was prepared in double distilled water, 2-3 ml ethanol was added and solution was stirred rigorously using magnetic stirrer. Liquid ammonia was then added in it very slowly, drop by drop, to maintain the pH of the solution up to 8.3 to 10. White precipitate obtained was collected and washed. This precipitate was then provided ultrasonic treatment for 6 hrs. followed by calcinations at 500^oC for 5 hrs. and finally, we get white powder of nanoscale SnO₂.

Composite samples of PANI-SnO₂ were prepared with three different molar concentrations of SnO_2 using in situ oxidative polymerization of aniline in presence of SnO_2 . Aniline (0.5M) was added to the solution of 1M HNO₃. In this

solution, initially prepared SnO₂ was added with various molar concentrations (0.5M, 0.25M, and 0.125M) for various composite samples of PANI-SnO₂. The solution was stirred continuously using magnetic stirrer. (0.1M) ammonium per sulphate was added. After 4 to 5 hrs. solution was turn to dark green color, which is an indication of oxidation of aniline. The solution was then allowed to stir for 24 hrs. Green color ppt obtained, was filtered, washed and dried at 80^oC for 2 hrs. The dark green powder samples of PANI-SnO₂ were obtained. These dry powder samples were transformed in to thick films using screen printing technique, as explained earlier in chapter 2. Fabricated thick films were fired at 100^oC.

II. (B) CHARACTERIZATION

These prepared samples were characterized by using X-ray diffraction measurements, with Rigaku diffractometer using CuKu (λ = 1.542 nm) radiation over 20 range from 20⁰ to 80⁰, UV-Visible spectroscopy using 300 to 1100 nm wave length, FTIR over 400 to 4000 cm⁻¹, was studied. The microscopy and micro-evaluations were performed with scanning electron microscopy technique (SEM& EDAX) and transmission electron microscopy. The electrical behavior and gas sensing performance of samples was checked.





Fig. 1: UV-Visible spectroscopy of PANI-SnO₂

Fig. 1 depicts the UV-Visible spectra of pure PANI and PANI-SnO₂ (0.25M) composite sample. Fig. 1 distinctly reveals broad band of pure PANI at 325 nm, which is attributed to π - π transition of Benznoid ring. This peak is followed by a shoulder rise at 450 nm indicating formation of positive radical cation during oxidation of monomer. Broad peaks of pure PANI at 650 nm, associated to π - polaron transition due to inter ring charge transfer due to excitation of Benznoid ring to Quinoid ring. It depends on oxidation state of PANI. UV absorption spectra of PANI- SnO₂ show π - π^* transition of Benznoid ring at 280 nm. A peak at 420 nm exhibits polaron- π^* transition. The peak at 800 nm is attributed to π -polaron transition. The characteristic peak of π - π^* and π -polaron transition at 280 nm and 800 nm respectively attributed to the doping level and formation of polaron. As compared with pure PANI, optical spectra of PANI-SnO₂ shows shift towards lower wavelength. In addition, it is observed the increased level of absorption for PANI-SnO₂ composite. This is characteristic property of oxide. This proves the incorporation of SnO₂ in PANI matrix. It confirms formation of PANI-SnO₂ nanocomposites.

III (B) FTIR SPECTROSCOPIC STUDIES

FTIR spectrum of pure PANI is explained in Fig. 5 (a) of chapter 2. Fig. 2 shows FTIR spectrum of PANI-SnO₂ nanocomposite, shows characteristics peak at ~2923 cm⁻¹ attributed to N-H stretching mode suggesting presence of N-H groups in aniline unit. The band at ~1599 cm⁻¹ is attributed to stretching vibrations in quinoid N=O=N ring. The band at ~1448 cm⁻¹ is attributed to stretching vibrations in Benznoid N=B=N ring. The band at 1299 cm⁻¹ is attributed to plane bending of C-H, formed during protonation. Peaks at 805 cm⁻¹ reveal the presence of SnO₂ particles exhibiting the shift of characteristic frequencies towards the lower side. In FTIR spectra of pure PANI and composite of PANI-SnO₂, similar bands are observed over the range 400 - 4000 cm⁻¹. This indicates that the main constituents of PANI and PANI-SnO₂ composite have same chemical structures. However, shift of characteristic peaks is observed in PANI-SnO₂ composite sample. Such a shift may be described due to the formation of hydrogen bonding between tin oxide and NH group of PANI on the surface of tin oxide [27].



Fig. 2: FTIR spectrograph of PANI-SnO₂

III (C) X-Ray diffraction study

Fig. 3 shows X-Ray diffraction graph of PANI, PANI-SnO₂ and CuO activated PANI-SnO₂. The XRD measurements were performed with BRUKER AXSD 8 (Germany) advance model X ray diffraction with CuK α_1 (λ =1.54056A⁰) radiation in the 2 θ range 20⁰- 80⁰. The XRD pattern of pure PANI, in Fig. 3 (a) indicates the prominent broad diffraction peak at 23.98⁰, suggesting the amorphous nature of PANI along with

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Fig. 3 (c): XRD pattern of CuO activated PANI-SnO2

55.4% crystallinity due to synthesis in strong acidic aqueous medium (1M HNO₃).

Fig. 3 (b and c) indicate XRD peaks of PANI-SnO₂ and CuO activated PANI-SnO₂, showing prominent peaks attributed to (110), (101), (200) and (211) planes at 26.57⁰, 33.8⁰, 37.95⁰ and 51.75⁰ respectively, which is attributed to typical tetragonal structure (JCPDS DATA CARD 41-1445). For tetragonal structure, lattice constants a = b, a and c are determined by using the formula:

$$\frac{1}{d^2} = \frac{\frac{1}{h^2 + \frac{1}{k^2}}}{a^2} + \frac{1^2}{c^2}$$

The average value of lattice parameters was found to be $a=b=4.74A^0$ and $c=3.186 A^0$. While standard bulk value for tin oxide crystalline structure is $a=b=4.738 A^0$ and $c=3.187 A^0$. This suggests that SnO₂ grains in the thick film are strained may be due to the average physical size of the grain themselves [28]. Average crystallite size was estimated by using Scherer's formula:

$$d = \frac{k\lambda}{\beta \cos\theta}$$

Where d is the crystallite size, k is 0.9, wavelength of X ray radiation $\lambda = 1.542$ A⁰ and θ is angle of diffraction. The crystallite size of PANI-SnO₂ nanocomposite is found to be ~ 6.8 nm. Fig. 3 (a-c) reveals the preferred orientation for SnO_2 is along the plane (110) [29-31]. It is observed from Fig 3 (b) that the XRD pattern of the PANI-SnO₂ nanocomposite exhibits the characteristic diffraction peaks of SnO₂ with 26.6% crystallinity and 73.4% amorphous nature due to PANI matrix. This indicates that the prepared nanocomposite sample of PANI-SnO₂ preserved crystalline nature of SnO₂ along with amorphous nature of PANI. This indicates that, as SnO2 was dispersed in reaction mixer during polymerization of aniline, the formation of PANI matrix takes place on the surface of SnO₂ nanoparticles. This exhibits core-shell structure of nanocomposite of PANI metal oxide nanocomposite (PANI-SnO₂), which is also analyzed by Transmission Electron Microscopic images. From Fig 3 (c), it is observed that, preferred orientation peak (110) [31-35] is attributed to presence of SnO₂ and hence it's crystal structure, do not get affected due to surface activation by CuO or no extra peaks in the XRD pattern of PANI-SnO₂ film were found, as it may be in very minute amount dispersed on the surface of film.

III (D) SURFACE MORPHOLOGY

The FESEM images of PANI-SnO₂ composite films of various concentrations of SnO₂ (0.5M, 0.25M, and 0.125M) are shown in Fig. 4 (a-c), while Fig. 4 (d-f) shows surface activation by CuO on dipping PANI-SnO₂ film with 0.25M concentration of SnO_2 in copper nitrate aqueous solution for 15 min. 30 min and 45 min. Many researchers showed that, SnO₂ nanoparticles exhibit a granular structure [28-33], while from Fig. 4 (a-f), it is observed that morphology of PANI-SnO₂ and CuO activated PANI-SnO₂ nanocomposite films are characterized by the presence of large globules. It is clearly visible that PANI gets deposited at the surface of SnO₂ and the secondary nucleation growth of PANI takes place on the already existing PANI. Thus, the results of XRD, FTIR, FESEM and TEM have provided clear evidence that polymerization of aniline has been successfully achieved on the surface of SnO₂ nanoparticles and leads to core-shell structure. Fig. 4 (a-c) shows the PANI-SnO₂ nanocomposite with agglomeration. Also, from Fig. 4 (a-c), it is observed that, as the SnO₂ concentration increases, the particle size is also increases. The average particle size was found to be of ~ 6.8 nm. It is observed that the average grain size measured by XRD and SEM were not matching. This may happened due to the fact that two or more crystallites may be fused together to form a particle and cannot be resolved by SEM profile, but XRD can resolve the particles easily [34]. The growth of nanoparticles and further aggregate formation of material may be followed by diffusion limited cluster aggregation type mechanism instead of reaction limited cluster aggregation mechanism. According to P. Sandkuhler et al [35], diffusion limited cluster aggregation type mechanism, every collision



Fig. 4: FESEM images of PANI SnO₂ (a)0.5M, (b)0.25M, (c) 0.125M and CuO activated PANI-SnO₂ (d) 15 min, (e) 30 min and (f) 45 min.

between two clusters results in the formation of a new cluster, followed by further aggregate formation. While in reaction limited cluster aggregation type mechanism, only a small fraction of all the collisions leads to the formation of new cluster. The SEM images support such growth of PANI-SnO₂ nanoparticles and further aggregate formation as a result of diffusion limited cluster aggregation mechanism. The surface activation of PANI-SnO₂ (with0.25M SnO₂) thick film by dipping in copper nitrate solution for 15 min. provides favorable surface morphology for gas response which leads to maximum ammonia response at room temperature.

III (E) EDAX ANALYSIS

The chemical composition analysis of PANI-SnO₂ thick films was performed by the energy dispersive analysis by Xray (EDAX). The EDAX analysis exhibits prominent peaks of Sn and O with C, N, O, etc. as organic counter part of aniline. No additional peaks are detected indicating that prepared samples are free from impurities that arise from starting precursors. The mass % of Sn and O varies with varying concentration of SnO₂ in the reaction mixture.

III (F) TRANSMISSION ELECTRON MICROSCOPY

Fig. 5 (a) shows TEM micrograph of $PANI-SnO_2$ as prepared powder sample.



Fig. 5 (a): Transmission Electron Micrograph of PANI-SnO₂ (0.25M)



Fig. 5 (b): Diffraction pattern of PANI-SnO₂ (0.25M)

It supports core shell spherical nanocrystal structure. The average particle size was found to be of ~ 9.37nm. The crystallite size observed by TEM is in good agreement with the value determined by SEM (~6.8 nm). The electron diffraction

pattern of PANI-SnO₂ in Fig. 5 (b) exhibits concentric rings made up of discrete spots indicating the nano-sized polycrystalline nature of as prepared sample. The crystalline structure corresponding to planes (110), (101), (220), (112) and (321) are consistent with the peaks observed in the XRD pattern. XRD and TEM studies confirmed tetragonal structure of SnO₂. The diameter of each ring of diffraction pattern is measured as 3.01 nm⁻¹, 3.5 nm⁻¹, 5.89 nm⁻¹, 6.96 nm⁻¹ and 8.09 nm⁻¹. The reciprocal of these values give the inter-planar distance d values. In table 1, d values from XRD and diffraction pattern of TEM are summarized.

XRD	Electron diffraction (TEM)		Plane
d values			(hkl)
(A ⁰)	Reciprocal of d values $\delta_{hkl} (nm^{-1})$	d values (A ⁰)	
3.351	3.01	3.32	110
2.644	3.5	2.8	101
1.75	5.89	1.69	220
1.439	6.96	1.436	112
1.215	8.09	1.236	321

Table 1: d values obtained from XRD and TEM

III (G) ELECTRICAL BEHAVIOR OF THE SENSOR

Fig. 6 depicts I-V characteristics of PANI SnO₂ composites with various concentrations of SnO₂. It exhibits the resistive or ohmic nature. PANI-SnO₂ (0.25 M) sample shows maximum conductivity (Fig. 7). The increase in conductivity may be attributed to the increase of charge transformation due increased surface: volume ratio, as shown in Fig. 4 (b) and may be due to reduced particle size as evidence by TEM image as shown in Fig. 5. It has been observed that, the conductivity of the samples increases with the operating temperature, showing negative temperature coefficient of resistance (NTC). Thus, the samples represent semiconducting nature. The increase in conductivity is due to the increase in charge transfer by contribution of polaron and bipolaron bands formation within wide band gap of composites between SnO₂ and PANI chain with increase in temperature [36].



Fig. 6: I-V characteristics of PANI SnO2



Fig. 7: Thermal characteristics of PANI SnO₂

IV GAS SENSING PERFORMANCE OF THE SENSOR IV (A) EFFECT OF OPERATING TEMPERATURE



Fig. 8 (a): NH_3 response vs. operating temperature of PANI-SnO₂ (0.25M)



Fig. 8 (b): NH_3 response vs. operating temperature of CuO activated (15 min) PANI-SnO₂(0.25M)

All adsorption, desorption and diffusion processes are temperature dependent, which are responsible for gas sensing mechanism of the sensor. It was observed from Fig. 8 that, gas response varies with change in operating temperature. Fig. 8 (a) shows variation of NH_3 response against operating temperature for different samples of PANI-SnO₂ with varying concentration of SnO₂, viz. 0.5M, 0.25M and 0.125M. The sensor with 0.25M concentration of SnO₂ incorporated in PANI matrix shows maximum response of 8.8 to ammonia gas at room temperature, among all. This sensor also shows considerable response (5.7) to ethanol, (2.2) to chlorine and (1.7) to CO₂ gas at room temperature.

All of these sensors show maximum response to NH_3 but suffering from poor selectivity (Fig. 10) against other gases, LPG, Ethanol, CO₂, H₂, Cl₂ and H₂S. The sensor was then surface activated by dipping it in to 0.01M copper nitrate solution for different intervals of time viz. 15 min, 30 min and 45 min. Fig. 8 (b) shows the variation of NH_3 gas response with operating temperature for CuO activated PANI-SnO₂ samples for different dipping time. Out of these, the sensor activated for 15 min shows maximum response of 11.7 to NH_3 gas at room temperature.

IV (B) ACTIVE REGION OF THE SENSOR



Fig. 9 (a): Variation in response with $\rm NH_3$ gas concentration in ppm for PANI- $\rm SnO_2$



Fig. 9 (b): Variation in response with NH_3 gas concentration in ppm for CuO activated PANI-SnO₂

When the PANI-SnO₂ thick film was exposed to varying concentration of NH₃, the gas response observed to increase continuously with increasing concentration of NH₃ at optimum temperature. Fig. 9 (a) shows variation of NH₃ gas response with ammonia gas concentration in ppm, for the sensor composite of PANI-SnO₂ at room temperature, Fig. 9 (b) shows variation of NH₃ response with ammonia gas concentration for CuO activated PANI-SnO₂ samples for 15 min., 30 min. and 45 min. dipping time. All the samples show initial rapid increase in gas response from 20 to 50 ppm and then saturates beyond 50 ppm. Thus active region for these samples is 20 ppm to 50 ppm. However, in case of CuO activated PANI-SnO₂ samples respond to NH₃ at 10 ppm. Thus the active region for these samples is from 10 ppm to 50 ppm of NH₃ at room temperature. It indicates that surface activation of PANI-SnO₂ with CuO (for 15 min dipping time) improves the active nature region. Exposure to large concentration of gas form multilayer of gas molecules on film surface, due to multilayers, gas molecules remain there as inactive molecules which slows down the rate of increase of gas response.

IV (C) SELECTIVITY OF THE SENSOR

Fig. 10 (a) depicts the selective nature of the PANI–SnO₂ sensor for 20 ppm NH₃ against various gases at room temperature. PANI–SnO₂ (0.25M) sensor shows maximum response to NH3 among all. However, it suffers from poor selectivity against ethanol and Cl₂ gases. It was observed in Fig. 10 (b) that, CuO activated PANI–SnO₂ (0.25M) for 15 min enhanced the response to NH₃ at room temperature. The same sample exhibits the considerable response to LPG and CO₂ among all other gases viz. LPG, NH₃, CO₂, Ethanol, H₂, Cl₂, and H₂S. Also, it was observed from Fig. 10 (b) that, after CuO activation for 15 min, PANI–SnO₂ (0.25M) sample enhances the LPG response than without activated film.



Fig. 10 (a): Selective nature of PANI-SnO₂



Fig. 10 (b): Selective nature of CuO activated PANI-SnO₂ for ammonia gas

IV (D) RESPONSE-RECOVERY PROFILE OF THE SENSOR



Fig.11: Response and recovery of the sensor



Fig.12: Long term stability of the sensor

Fig. 11 shows response and recovery time of PANI-SnO₂ sample with SnO₂ concentration of (0.25M) and CuO activated PANI-SnO₂ which is dipped in copper nitrate solution for 15 min. It was observed that, the sensor shows quick response (~4 s) to 20 ppm NH₃ and fast recovery (~15 s).

IV (E) LONG TERM STABILITY OF THE SENSOR

To ensure the reliability, important parameter of gas sensors is their stability over long duration. It reduces uncertainty in the results and improves the durability of sensor. Hence it is essential to pay attention towards long term stability of gas sensor. Mainly pure PANI is highly reactive and shows changes in oxidation states in open air atmosphere which leads to poor long term stability. Stability of the sensor films can be extended by doping PANI with inorganic elements, post processing treatments like annealing and capping sensor film surface with certain element. It is observed from Fig. 12 that, PANI-SnO₂ (0.25M) shows 23.34% decrease in the gas response within 150 days. However, CuO activated sample with dipping time of 15 min. shows 8.56% decrease within 60 days then after preferably remains constant.

IV (F) AMMONIA SENSING MECHANISM

The physical properties of conducting polymers strongly depend on their doping levels. Fortunately, the doping levels of conducting polymers can be easily changed by chemical reactions with many analytes at room temperature. This provides a simple technique to detect the analytes. Most of the conducting polymers are doped / undoped by redox reactions. Therefore, their doping level can be altered by transferring electrons from or to the analytes. Electron transferring can cause the changes in resistance and work function of the sensing material. This process occurred when thick films of PANI are exposed with NH₃ and other redox-active gases. Electron acceptors can remove electrons from the aromatic rings of conducting polymers. When this occurs at a p-type conducting polymer, the doping level as well as the electric conductance of the conducting polymer is enhanced. An opposite process will occur when detecting an electron donating gas. Ammonia is an electron donor gas.

CONCLUSIONS

- 1. Pure PANI is insensitive to NH₃ gas even at higher gas concentration (1000 ppm).
- 2. Pure PANI can be loaded by post-transition metal oxide (SnO₂) as an additive, by the low cost technique.
- 3. Optimized mass% of CuO as an activator in PANI-SnO₂ enhances the NH₃ gas sensing performance of the sensor.
- 4. Among the various metal oxide additives tested, CuO activated SnO₂ loaded PANI is outstanding in promoting the NH₃ gas sensing performance of the material.

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